

# HD74LV4051A

8-channel Analog Multiplexer / Demultiplexer

# HITACHI

ADE-205-283 (Z)  
1st Edition  
April 1999

## Description

The HD74LV4051A handles both analog and digital signals, and enables signals of either type with amplitudes of up to 5.5 V (peak) to be transmitted in either direction (at  $V_{CC} = 0\text{ V}$  to 5.5 V). Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

## Features

- $V_{CC} = 2.0\text{ V}$  to 5.5 V operation
- All inputs  $V_{IH}(\text{Max.}) = 5.5\text{ V}$  (@  $V_{CC} = 0\text{ V}$  to 5.5 V)

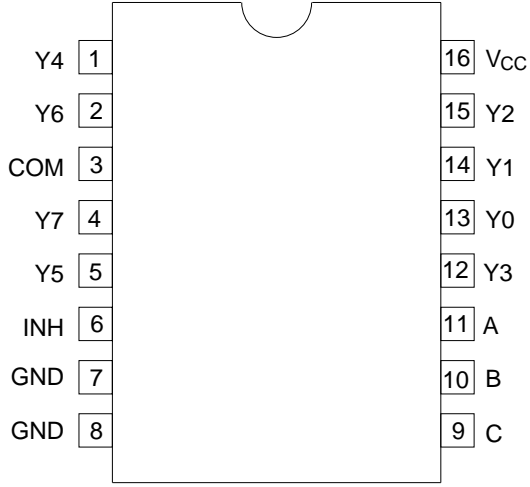
## Function Table

### Inputs

INH	C	B	A	On Channel
L	L	L	L	Y0
L	L	L	H	Y1
L	L	H	L	Y2
L	L	H	H	Y3
L	H	L	L	Y4
L	H	L	H	Y5
L	H	H	L	Y6
L	H	H	H	Y7
H	X	X	X	NONE

Note: H: High level  
L: Low level  
X: Immaterial

## Pin Arrangement



(Top view)

**Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V	
Input voltage range* <sup>1</sup>	$V_I$	-0.5 to 7.0	V	
Output voltage range* <sup>1,2</sup>	$V_O$	-0.5 to $V_{CC} + 0.5$	V	Output: H or L
Input clamp current	$I_{IK}$	-20	mA	$V_I < 0$
Output clamp current	$I_{OK}$	$\pm 50$	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	$I_O$	$\pm 25$	mA	$V_O = 0$ to $V_{CC}$
Continuous current through $V_{CC}$ or GND	$I_{CC}$ or $I_{GND}$	$\pm 50$	mA	
Maximum power dissipation at $T_a = 25^\circ\text{C}$ (in still air)* <sup>3</sup>	$P_T$	785	mW	SOP
		500		TSSOP
Storage temperature	$T_{stg}$	-65 to 150	$^\circ\text{C}$	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded even if the input and output clamp-current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

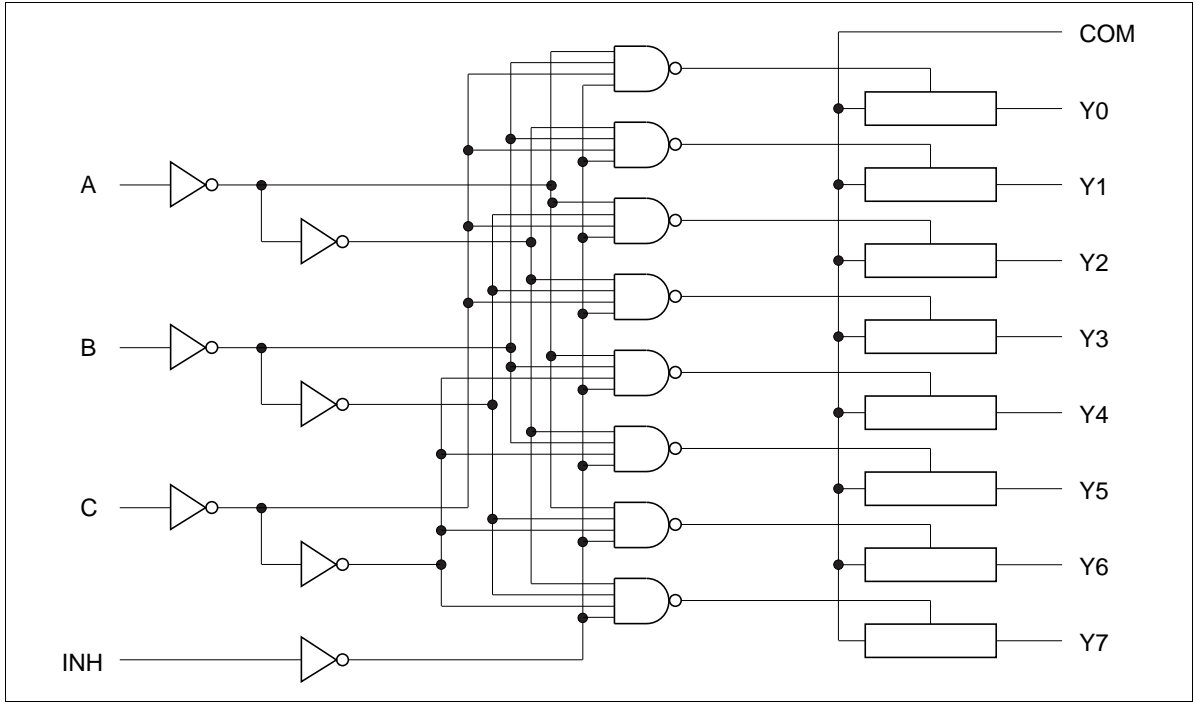
**Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	$V_{CC}$	2.0* <sup>1</sup>	5.5	V	
Input voltage range	$V_I$	0	5.5	V	
Output voltage range	$V_{IO}$	0	$V_{CC}$	V	
Input transition rise or fall rate	$\Delta t / \Delta v$	0	200	ns/V	$V_{CC} = 2.3$ to $2.7$ V
		0	100		$V_{CC} = 3.0$ to $3.6$ V
		0	20		$V_{CC} = 4.5$ to $5.5$ V
Operating free-air temperature	$T_a$	-40	85	$^\circ\text{C}$	

Notes: Unused or floating inputs must be held high or low.

1. With the supply voltage at or around 2 V, the analog switch on-state loses linearity significantly. It is recommended that only digital signals be transmitted at these low supply voltages.

**Logic Diagram**



**DC Electrical Characteristics**

Item	Symbol	V <sub>CC</sub> (V)*	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Input voltage	V <sub>IH</sub>	2.0	—	—	—	1.5	—	V	
		2.3 to 2.7	—	—	—	V <sub>CC</sub> × 0.7	—		
		3.0 to 3.6	—	—	—	V <sub>CC</sub> × 0.7	—		
		4.5 to 5.5	—	—	—	V <sub>CC</sub> × 0.7	—		
	V <sub>IL</sub>	2.0	—	—	—	—	0.5		
		2.3 to 2.7	—	—	—	—	V <sub>CC</sub> × 0.3		
		3.0 to 3.6	—	—	—	—	V <sub>CC</sub> × 0.3		
		4.5 to 5.5	—	—	—	—	V <sub>CC</sub> × 0.3		
On-state switch resistance	R <sub>ON</sub>	2.3	—	60	180	—	225	Ω	V <sub>IN</sub> = V <sub>CC</sub> or GND V <sub>INH</sub> = V <sub>IL</sub> I <sub>T</sub> = 2 mA
		3.0	—	50	150	—	190		
		4.5	—	40	75	—	100		
Peak on resistance	R <sub>ON(P)</sub>	2.3	—	200	500	—	600	Ω	V <sub>IN</sub> = V <sub>CC</sub> to GND V <sub>INH</sub> = V <sub>IL</sub> I <sub>T</sub> = 2 mA
		3.0	—	90	180	—	225		
		4.5	—	50	100	—	125		
Difference of on-state resistance between switches	ΔR <sub>ON</sub>	2.3	—	20	30	—	40	Ω	V <sub>IN</sub> = V <sub>CC</sub> to GND V <sub>INH</sub> = V <sub>IL</sub> I <sub>T</sub> = 2 mA
		3.0	—	10	20	—	30		
		4.5	—	7	15	—	20		
Off-state switch leakage current	I <sub>s</sub> (OFF)	5.5	—	—	±0.1	—	±1.0	μA	V <sub>IN</sub> = V <sub>CC</sub> , V <sub>OUT</sub> = GND or V <sub>IN</sub> = GND, V <sub>O</sub> = V <sub>CC</sub> , V <sub>INH</sub> = V <sub>IH</sub>
On-state switch leakage current	I <sub>s</sub> (ON)	5.5	—	—	±0.1	—	±1.0	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND V <sub>INH</sub> = V <sub>IL</sub>
Input current	I <sub>IN</sub>	0 to 5.5	—	—	±0.1	—	±1.0	μA	V <sub>IN</sub> = 5.5 V or GND
Quiescent supply current	I <sub>CC</sub>	5.5	—	—	—	—	20	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

## Switching Characteristics

- $V_{CC} = 2.5 \pm 0.2 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)	
		Min	Typ	Max	Min	Max					
Propagation delay time	$t_{PLH}$	—	3.5	10.0	—	16.0	ns	$C_L = 15 \text{ pF}$	COM or Yn	Yn or COM	
	$t_{PHL}$	—	6.0	12.0	—	18.0					$C_L = 50 \text{ pF}$
Enable time	$t_{ZH}$	—	8.0	18.0	—	23.0	ns	$R_L = 1 \text{ k}\Omega$	$C_L = 15 \text{ pF}$	INH	COM or Yn
	$t_{ZL}$	—	9.0	28.0	—	35.0					
Disable time	$t_{HZ}$	—	12.0	18.0	—	23.0	ns	$R_L = 1 \text{ k}\Omega$	$C_L = 15 \text{ pF}$	INH	COM or Yn
	$t_{LZ}$	—	14.0	28.0	—	35.0					

- $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)	
		Min	Typ	Max	Min	Max					
Propagation delay time	$t_{PLH}$	—	2.5	6.0	—	10.0	ns	$C_L = 15 \text{ pF}$	COM or Yn	Yn or COM	
	$t_{PHL}$	—	4.5	9.0	—	12.0					$C_L = 50 \text{ pF}$
Enable time	$t_{ZH}$	—	6.0	12.0	—	15.0	ns	$R_L = 1 \text{ k}\Omega$	$C_L = 15 \text{ pF}$	INH	COM or Yn
	$t_{ZL}$	—	7.0	20.0	—	25.0					
Disable time	$t_{HZ}$	—	8.0	12.0	—	15.0	ns	$R_L = 1 \text{ k}\Omega$	$C_L = 15 \text{ pF}$	INH	COM or Yn
	$t_{LZ}$	—	11.0	20.0	—	25.0					

**Switching Characteristics (cont)**

- $V_{CC} = 5.0 \pm 0.5 \text{ V}$

**Ta = 25°C**
**Ta = -40 to 85°C**

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)	
		Min	Typ	Max	Min	Max					
Propagation delay time	$t_{PLH}$	—	2.0	4.0	—	7.0	ns	$C_L = 15 \text{ pF}$	COM or Yn	Yn or COM	
	$t_{PHL}$	—	3.0	6.0	—	8.0					$C_L = 50 \text{ pF}$
Enable time	$t_{ZH}$	—	4.0	8.0	—	10.0	ns	$R_L = 1 \text{ k}\Omega$	$C_L = 15 \text{ pF}$	INH	COM or Yn
	$t_{ZL}$	—	5.5	14.0	—	18.0					
Disable time	$t_{HZ}$	—	5.0	8.0	—	10.0	ns	$R_L = 1 \text{ k}\Omega$	$C_L = 15 \text{ pF}$	INH	COM or Yn
	$t_{LZ}$	—	8.5	14.0	—	18.0					

## Switching Characteristics (cont)

Item	Symbol	V <sub>CC</sub> (V)	Ta = 25°C			Unit	Test Conditions	FROM (Input)	TO (Output)
			Min	Typ	Max				
Control input capacitance	C <sub>IC</sub>	—	—	4.0	—	pF			
Common terminal capacitance	C <sub>IS</sub>	—	—	35.5	—	pF			
Switch terminal capacitance	C <sub>I/O</sub>	—	—	7.0	—	pF			
Feedthrough capacitance	C <sub>T</sub>	—	—	0.5	—	pF			
Power dissipation capacitance	C <sub>PD</sub>	—	—	11.0	—	pF			
Frequency response (Switch ON)		2.3	—	20.0	—	MHz	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 600 Ω Adjust f <sub>in</sub> voltage to obtain 0 dBm at output when f <sub>in</sub> is 1 MHz (sine wave). Increase f <sub>in</sub> frequency until the dB-meter reads -3 dBm. 20 log (V <sub>O</sub> /V <sub>I</sub> ) = -3 dBm	COM or Yn	Yn or COM
		3.0	—	25.0	—				
		4.5	—	35.0	—				
Crosstalk (Control input to signal output)		2.3	—	20.0	—	mV	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 600 Ω Adjust the R <sub>L</sub> value to obtain 0 A at I <sub>IN/OUT</sub> when f <sub>in</sub> is 1 MHz (square wave).	INH	COM or Yn
		3.0	—	35.0	—				
		4.5	—	60.0	—				
Feedthrough attenuation (Switch OFF)		2.3	—	-45	—	dB	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 600 Ω Adjust f <sub>in</sub> voltage to obtain 0 dBm at input when f <sub>in</sub> is 1 MHz (sine wave).	COM or Yn	Yn or COM
		3.0	—	-45	—				
		4.5	—	-45	—				



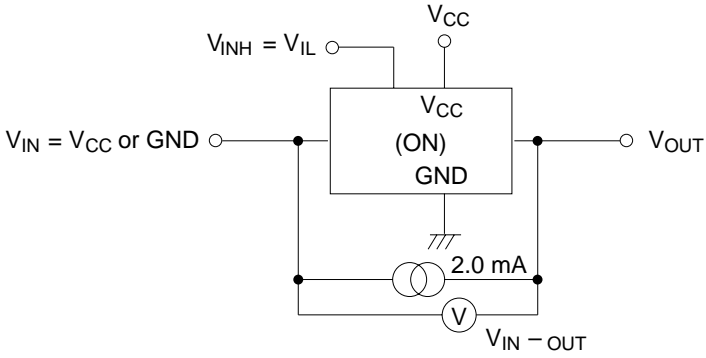
Switching Characteristics (cont)

Ta = 25°C

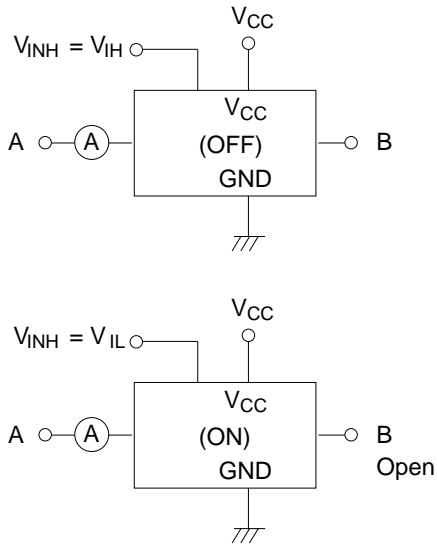
Item	Symbol	V <sub>CC</sub> (V)	Min	Typ	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Sine-wave distortion		2.3	—	0.1	—	%	C <sub>L</sub> = 50 pF, R <sub>L</sub> = 10 kΩ f <sub>IN</sub> = 1 kHz (sine wave) V <sub>I</sub> = 2 V <sub>P-P</sub> , V <sub>CC</sub> = 2.3 V V <sub>I</sub> = 2.5 V <sub>P-P</sub> , V <sub>CC</sub> = 3.0 V V <sub>I</sub> = 4 V <sub>P-P</sub> , V <sub>CC</sub> = 4.5 V	COM or YN	Yn or COM
		3.0	—	0.1	—				
		4.5	—	0.1	—				

## Test Circuits

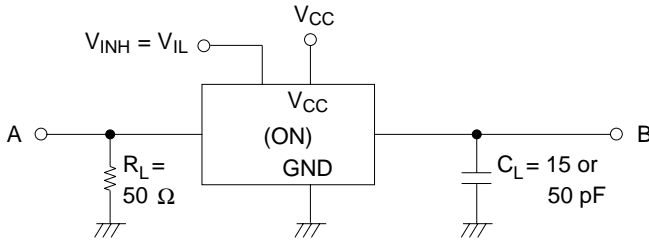
RON: On-state switch resistance



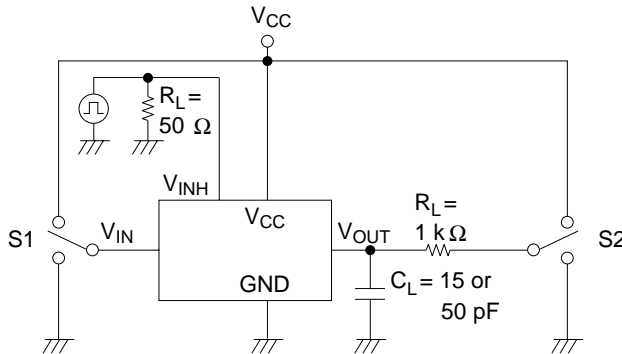
Is (OFF): Off-state switch leakage current, Is (ON): On-state switch leakage current.



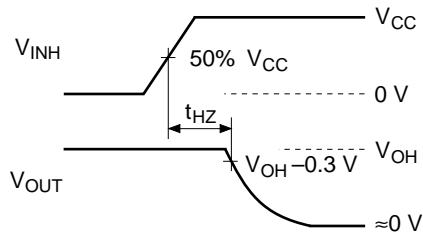
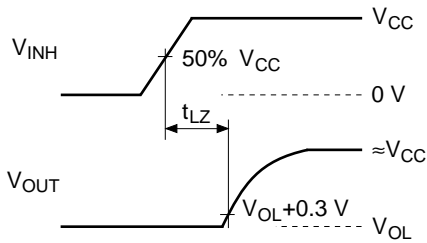
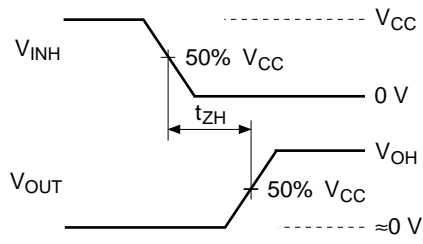
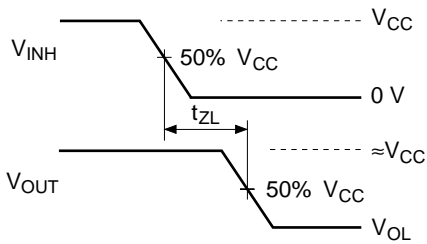
$t_{PLH}$ ,  $t_{PHL}$ : Propagation delay time (from switch input to switch output)



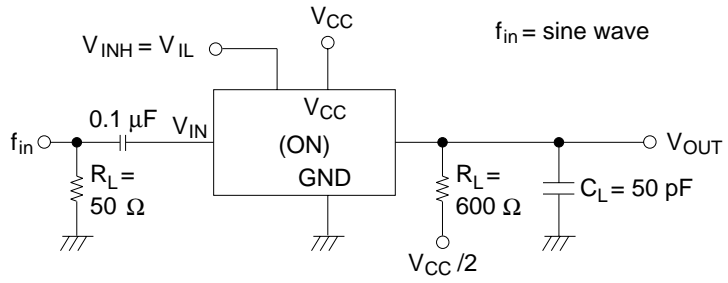
Switching time



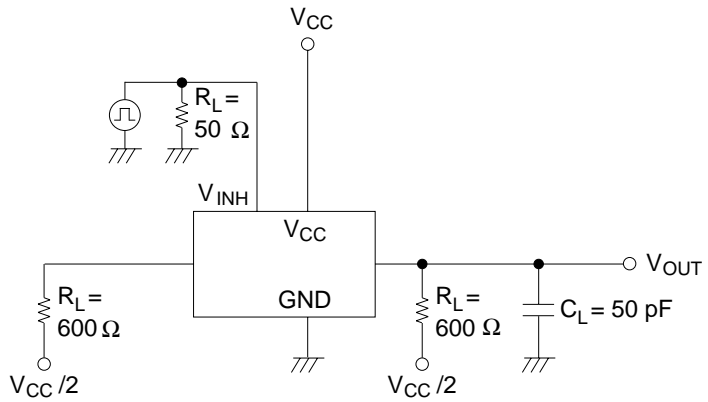
TEST	S1	S2
$t_{LZ}/t_{ZL}$	GND	VCC
$t_{HZ}/t_{ZH}$	VCC	GND



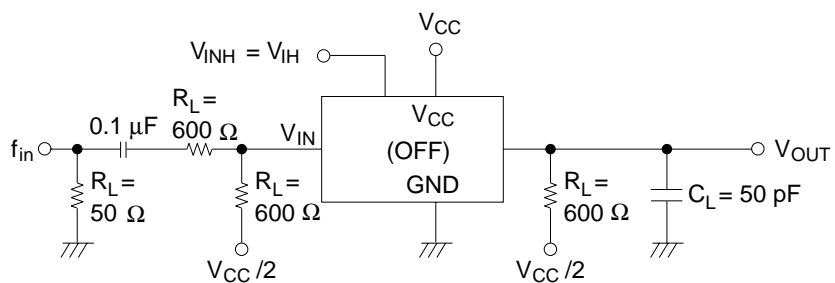
## Frequency response (switch ON)



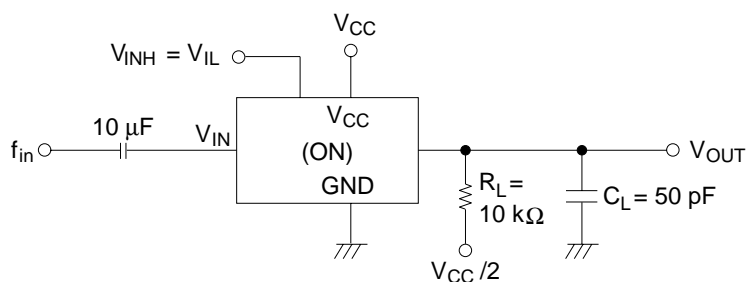
## Crosstalk (control input to switch output)



Feedthrough attenuation (switch OFF)

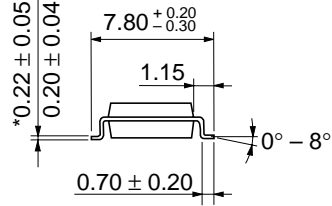
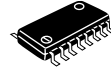
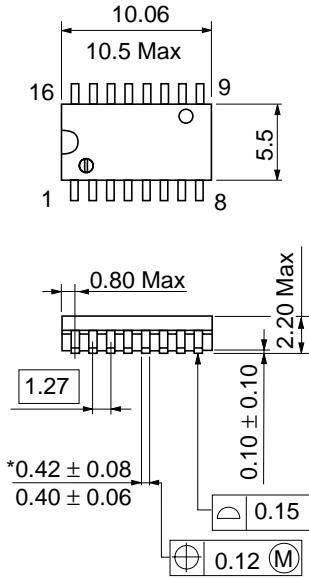


Sine-wave distortion



## Package Dimensions

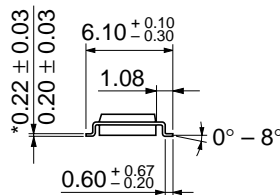
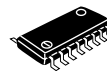
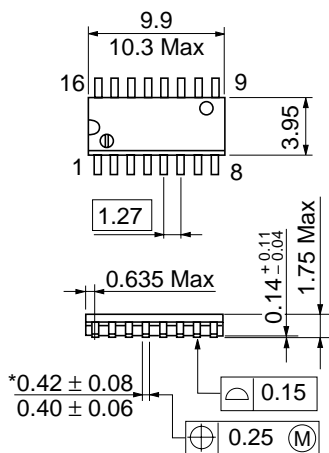
Unit: mm



\*Dimension including the plating thickness  
Base material dimension

Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g

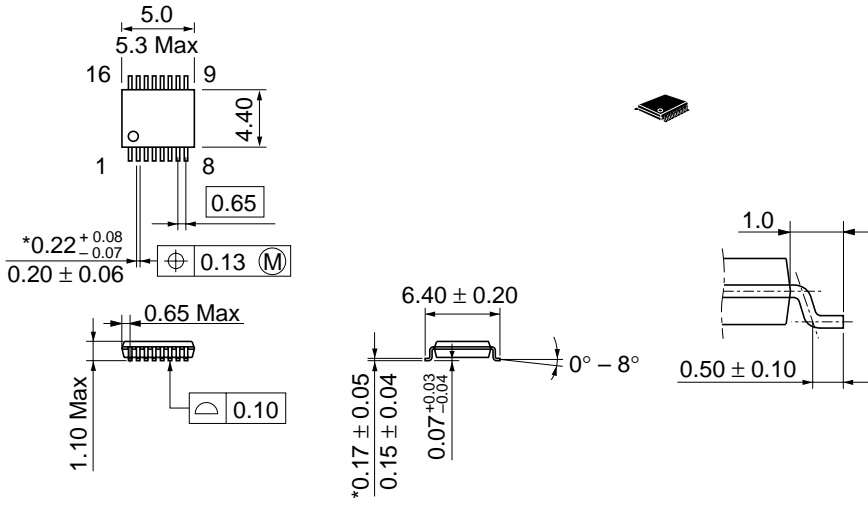
Unit: mm



\*Dimension including the plating thickness  
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

Unit: mm



\*Dimension including the plating thickness  
Base material dimension

Hitachi Code	TTP-16DA
JEDEC	—
EIAJ	—
Weight (reference value)	0.05 g



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